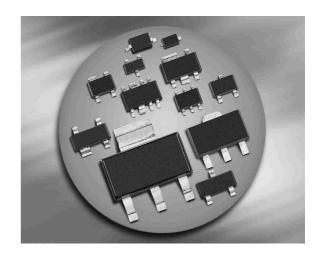


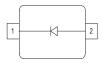
Silicon Variable Capacitance Diode

- For VHF TV / VTR tuners
- Pb-free (RoHS compliant) package





BB640



Туре	Package	Configuration	L S(nH)	Marking
BB640	SOD323	single	1.8	red S

Maximum Ratings at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Value	Unit V	
Diode reverse voltage	V_{R}	30		
Peak reverse voltage	V_{RM}	35		
($R \ge 5 \mathrm{k}\Omega$)				
Forward current	I _F	20	mA	
Operating temperature range	T_{op}	-55 150	°C	
Storage temperature	$T_{ m stg}$	-55 150		

1



Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

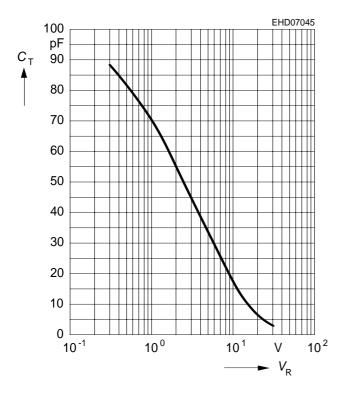
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Reverse current	I_{R}				nA
<i>V</i> _R = 30 V		-	-	10	
V_{R} = 30 V, T_{A} = 85 °C		-	-	200	
AC Characteristics	_	_			
Diode capacitance	C _T				pF
$V_{R} = 1 \text{ V}, f = 1 \text{ MHz}$		62	69	76	
$V_{R} = 2 \text{ V}, f = 1 \text{ MHz}$		47.5	54.5	61.5	
V_{R} = 25 V, f = 1 MHz		2.85	3.28	3.7	
V_{R} = 28 V, f = 1 MHz		2.8	3.05	3.3	
Capacitance ratio	C _{T1} /C _{T28}	19.5	-	25	
V_{R} = 1 V, V_{R} = 28 V, f = 1 MHz					
Capacitance ratio	C _{T2} /C _{T25}	15	16.6	-	
V_{R} = 2 V, V_{R} = 25 V, f = 1 MHz					
Capacitance matching ¹⁾	$\Delta C_{T}/C_{T}$	-	-	2.5	%
V_{R} = 1 V, V_{R} = 28 V, f = 1 MHz					
Series resistance	$r_{\rm S}$	-	1.15	_	Ω
C _T = 12 pF, f = 100 MHz					

¹For details please refer to Application Note 047.

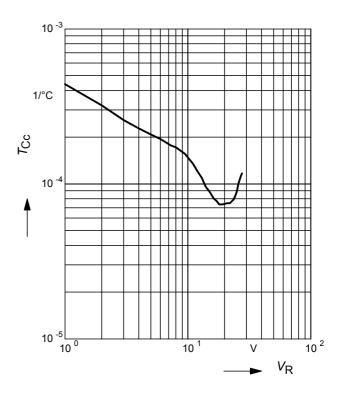


Diode capacitance $C_T = f(V_R)$

f = 1MHz

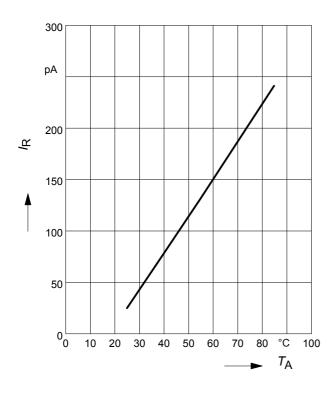


Temperature coefficient of the diode capacitance $T_{Cc} = f(V_R)$



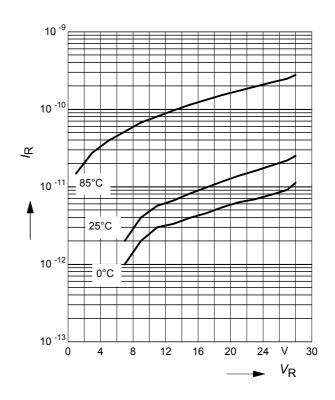
Reverse current $I_R = f(T_A)$

 $V_{R} = 28V$



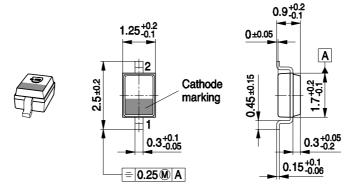
Reverse current $I_R = f(V_R)$

 T_A = Parameter

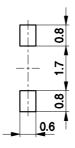




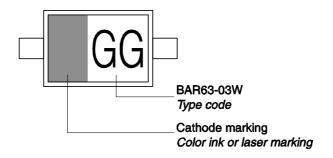
Package Outline



Foot Print

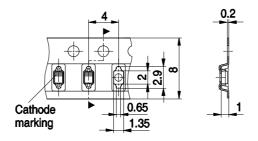


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





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